

### Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

#### Features

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 150°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



\* In compliance with EU RoHs 2002/95/EC directives

#### MAXIMUM RATINGS

Characteristic	Symbol	SRF20120	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	120	V
RMS Reverse Voltage	$V_{R(RMS)}$	84	V
Average Rectifier Forward Current (per diode) Total Device (Rated $V_R$ ), $T_C=100^\circ\text{C}$	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate $V_R$ , Square Wave, 20kHz)	$I_{FM}$	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	$I_{FSM}$	200	A
Operating and Storage Junction Temperature Range	$T_J$ , $T_{stg}$	-65 to +150	$^\circ\text{C}$

#### THERMAL RESISTANCES

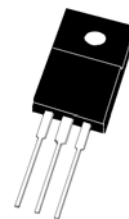
Typical Thermal Resistance junction to case	$R_{\theta j-c}$	3.5	$^\circ\text{C}/\text{w}$
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#### ELECTRIAL CHARACTERISTICS

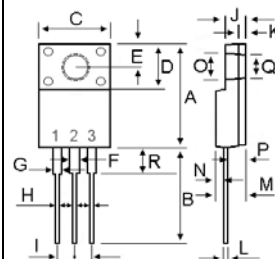
Characteristic	Symbol	SRF20120	Unit
Maximum Instantaneous Forward Voltage ( $I_F=10$ Amp $T_C=25^\circ\text{C}$ ) ( $I_F=10$ Amp $T_C=125^\circ\text{C}$ )	$V_F$	0.85 0.78	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C=25^\circ\text{C}$ ) (Rated DC Voltage, $T_C=125^\circ\text{C}$ )	$I_R$	0.2 20	mA

#### SCHOTTKY BARRIER RECTIFIERS

**20 AMPERES  
120 VOLTS**



ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80

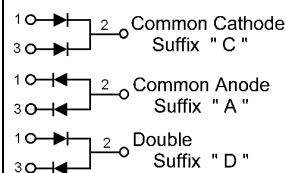


FIG-1 FORWARD CURRENT DERATING CURVE

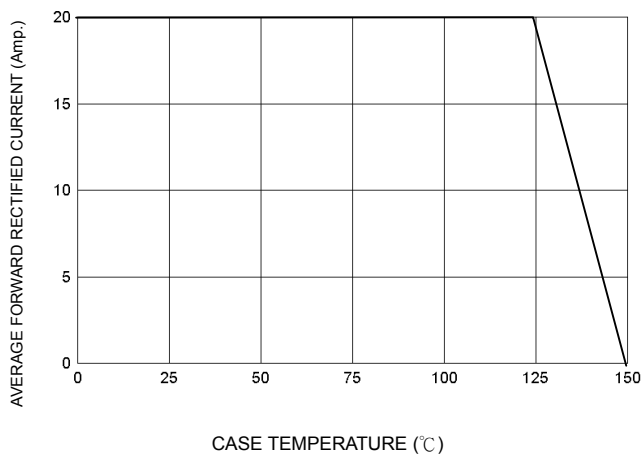


FIG-2 TYPICAL FORWARD CHARACTERISTICS

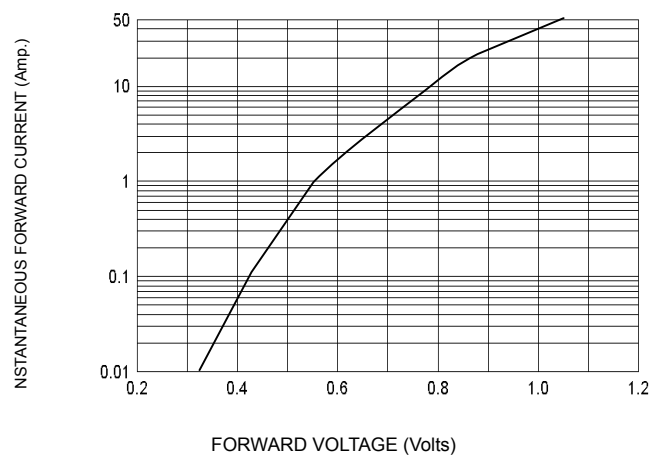


FIG-3 TYPICAL REVERSE CHARACTERISTICS

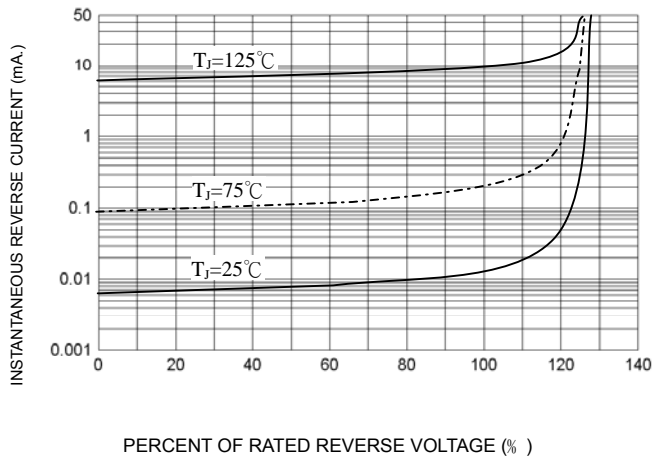


FIG-4 TYPICAL JUNCTION CAPACITANCE

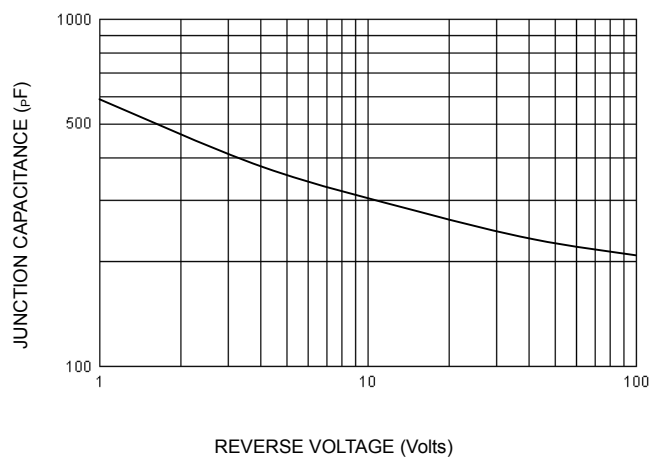
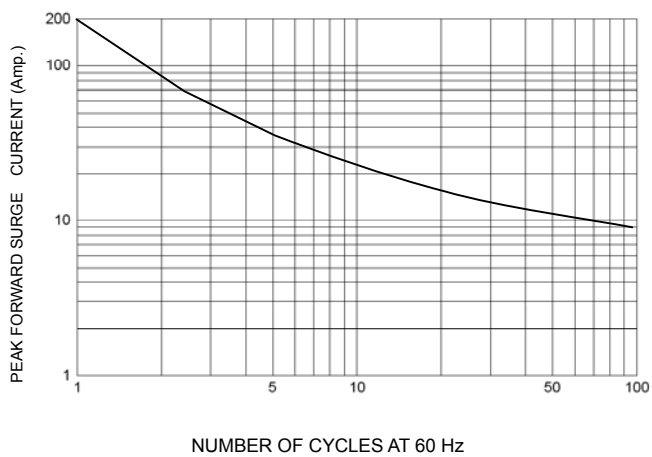


FIG-5 PEAK FORWARD SURGE CURRENT



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